

HIGH POWER BIAS TEE

BTN2-0050

The BTN2-0050 is constructed using a custom-made, resonance-free conical inductor to achieve extremely broadband performance. By minimizing the overall inductor size and using proprietary packaging techniques, the BTN2-0050 is a superior option in terms of performance, reliability and ease-of-use when compared to cumbersome user-designed bias tees employing off-the-shelf conical inductors. The extremely low cutoff and resonance free operation makes the BTN2-0050 suitable for biasing amplifiers, lasers, and modulators driven with high frequency data patterns.



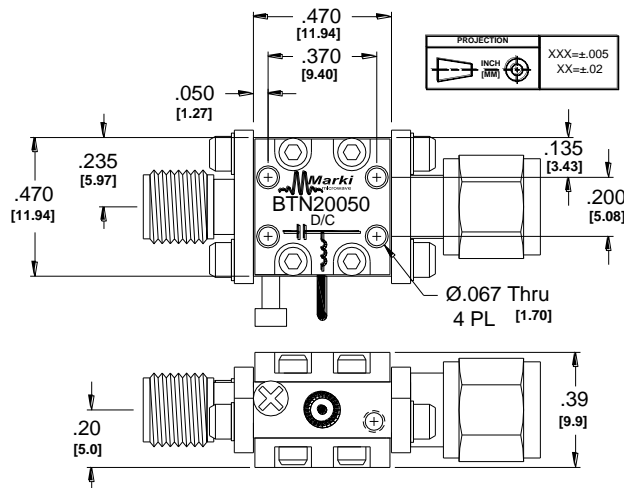
Features

- Broadband: 3 MHz to 50 GHz
- Low Insertion Loss
- High Power
- Non-Resonant
- Compact Size

Electrical Specifications - Specifications guaranteed from -55 to +100°C, measured in a 50Ω system.

Parameter	Frequency Range	Min	Typ	Max
Insertion Loss (dB)	10 MHz-50 GHz		1.5	2.5
	3-10 MHz		2	
DC Port Isolation (dB)	3 MHz -1 GHz		50	
	1-50 GHz		30	
Return Loss (dB)	3 MHz-50 GHz		13	
RF Power (W)				5
DC Current (A)				2
DC Voltage (V)				50
DC Resistance (Ω)			0.3	
Risetime /Falltime (ps) ¹			10	

¹Specified as 90%/10%. Calculated from $\tau_{bt}^2 = (\tau_{out}^2 - \tau_{in}^2)$

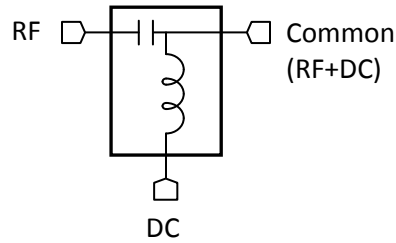


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Schematic



Application Examples

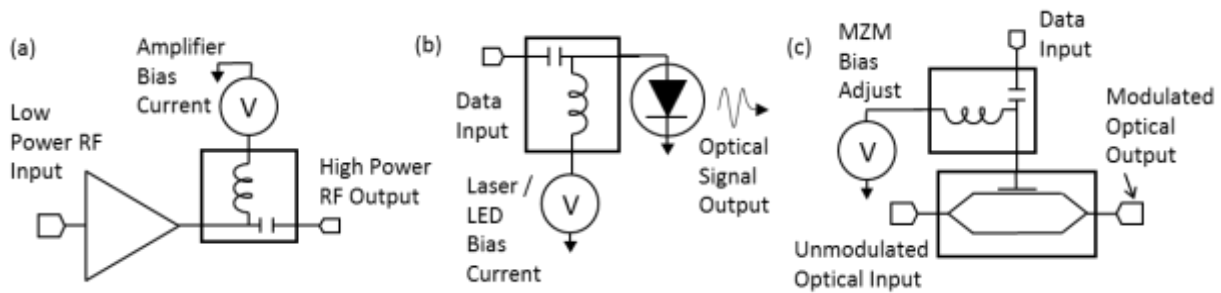


Fig. 1. Example Schematics of a) Broadband Microwave Amplifier Biasing, b) Laser/LED Biasing for Data Communication and c) Mach-Zender Modulator Biasing for Data Communication

Typical Performance

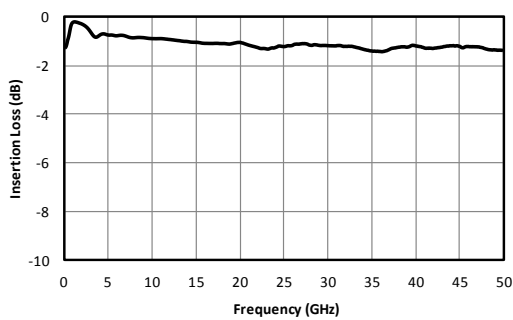


Fig. 2. RF insertion loss.

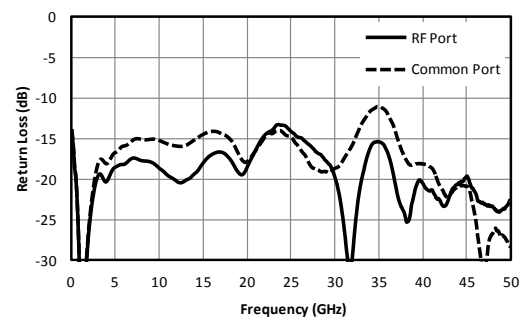


Fig. 3. Return loss.

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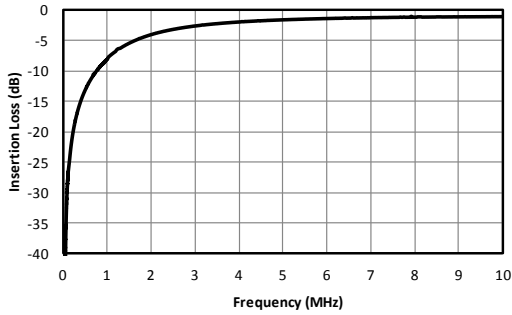


Fig. 4. Low frequency RF response.

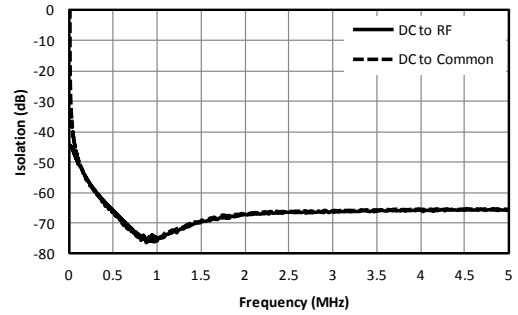


Fig. 5. Low frequency isolation.

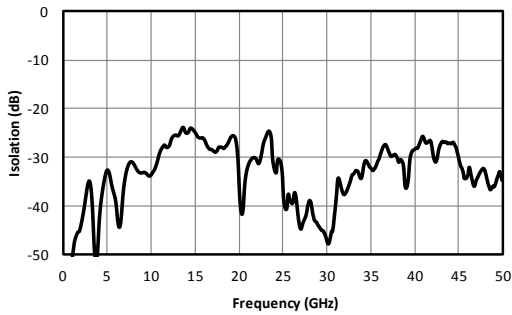


Fig. 6. DC-RF isolation.

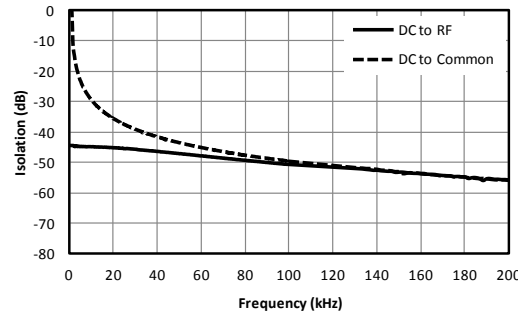


Fig. 7. Near DC isolation

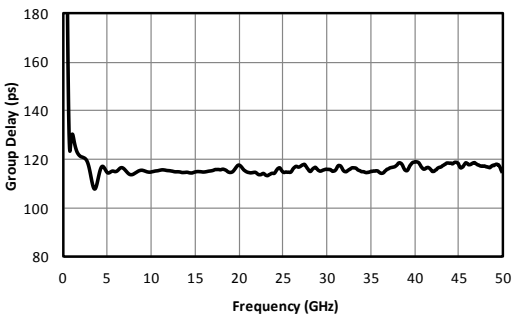


Fig. 8. Group delay.

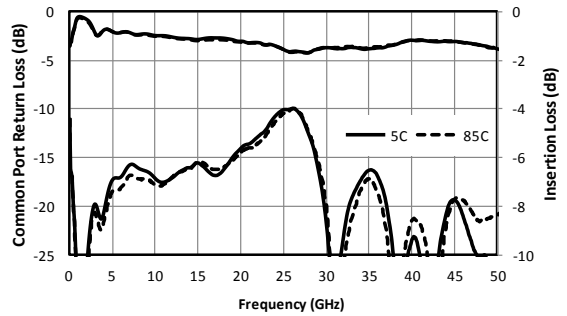


Fig. 9. Performance over temperature

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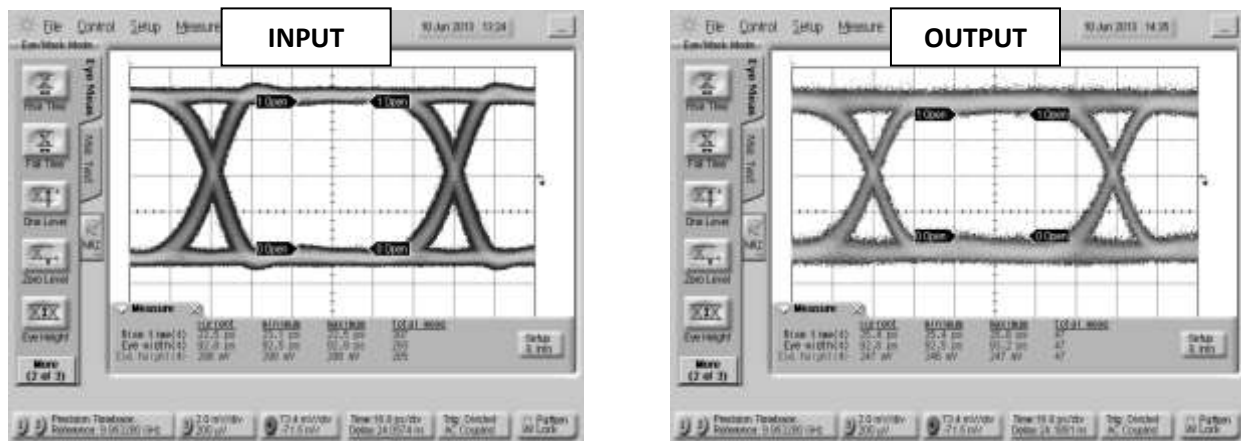


Fig. 7. Oscilloscope measurements of the BTN2-0050 with a 10Gb/s PRBS pattern. Eye diagrams are taken with a $2^{31}-1$ PRBS input demonstrating minimal eye distortion/closure afforded by the extremely low frequency operation of the bias tee.

Model Number	Description
BTN2-0050	3 MHz to 50 GHz High Power Bias Tee with 2.4 mm connectors ¹

¹Consult factory for other connector options.

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